Triacs BTA140B series

GENERAL DESCRIPTION

Glass passivated triacs in a plastic envelope suitable surface for mounting, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal performance. cycling **Typical** applications include motor control, industrial and domestic lighting, heating and static switching.

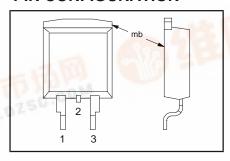
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{DRM} I _{T(RMS)} I _{TSM}	Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	500 500 25 190	600 600 25 190	800 800 25 190	V A A

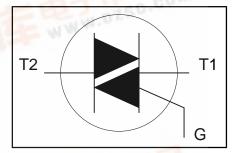
PINNING - SOT404

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
mb	main terminal 2

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	WW	MAX.		UNIT
V_{DRM}	Repetitive peak off-state voltages	可以		-500 500 ¹	-600 600 ¹	-800 800	V
$\mathbf{I}_{T(RMS)}\\\mathbf{I}_{TSM}$	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 91 ^{\circ}\text{C}$ full sine wave; $T_{j} = 25 ^{\circ}\text{C}$ prior to surge	-		25		А
192	FEE I	t = 20 ms t = 16.7 ms	-		190 209		A
l²t dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after	t = 10.7 ms t = 10 ms $I_{TM} = 30 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	da=	180		A A ² s
	triggering	T2+ G+ T2+ G- T2- G- T2- G+	TE.	MM	50 50 50 10		A/μs A/μs A/μs A/μs
I _{GM} V _{GM} P _{GM}	Peak gate current Peak gate voltage Peak gate power	ZSC.COM	- - -		2 5 5		Á V W
P _{G(AV)} T _{stg}	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125		ο̈́ο

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th i-mb}	Thermal resistance	full cycle	-	-	1.0	K/W
,	junction to mounting base	half cycle	-	-	1.4	K/W
$R_{th i-a}$	Thermal resistance	minimum footprint, FR4 board	-	55	-	K/W
,	liunction to ambient			1		l

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$				
		T2+ G+	-	6	35	mΑ
		T2+ G-	-	10	35	mA
		T2- G-	-	11	35	mΑ
		T2- G+	-	23	70	mA
I _L	Latching current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$				
		T2+ G+	-	8	40	mA
		T2+ G-	-	30	60	mA
		T2- G-	-	18	40	mĄ
1.	I lalella a accumant	T2- G+	-	15	60	mA
I _H	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$		_	20	A
		T2+ T2-	-	7 12	30	mA
1,,	On state valtage	· -	-		30	mA V
V_{T}	On-state voltage	$I_T = 30 \text{ A}$	-	1.2	1.55	V I
V_{GT}	Gate trigger voltage	$\dot{V}_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $\dot{V}_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_L = 125 °C$	0.25	0.7	1.5	l v
1,	Off state leakage gurrent	$V_D = 400 \text{ V}, I_T = 0.1 \text{ A}, I_j = 125 \text{ C}$ $V_D = V_{DRM(max)}; T_j = 125 \text{ °C}$	0.25	_	0.5	· ·
I _D	Off-state leakage current	$V_D = V_{DRM(max)}, I_j = 125 C$	-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	100	300	-	V/μs
dV _{com} /dt	off-state voltage Critical rate of change of commutating voltage	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}$; $T_j = 95 \text{ °C}$; $I_{T(RMS)} = 25 \text{ A}$; $dI_{com}/dt = 9 \text{ A/ms}$; gate open circuit	-	10	-	V/μs
t _{gt}	Gate controlled turn-on time	$I_{TM} = 30 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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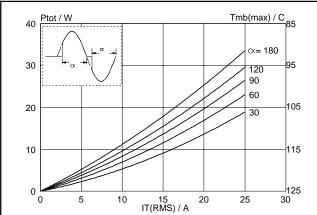


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where $\alpha = conduction$ angle.

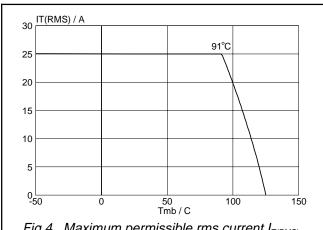


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

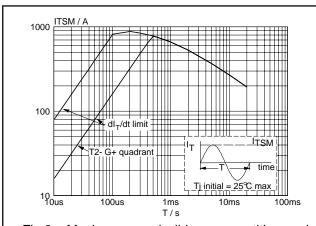


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20$ ms.

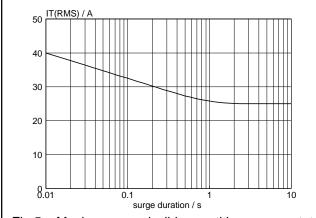


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 91$ °C.

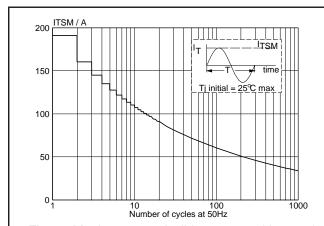


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, f = 50 Hz.

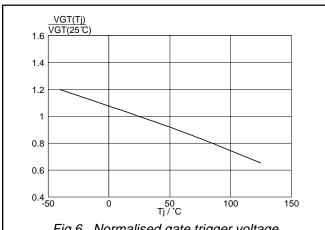
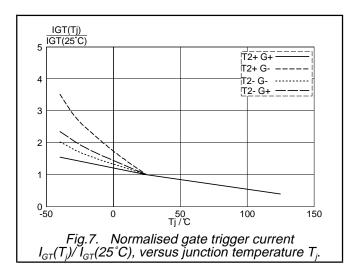


Fig.6. Normalised gate trigger voltage $V_{GT}(T_j)/V_{GT}(25^{\circ}C)$, versus junction temperature $T_{j\cdot}$

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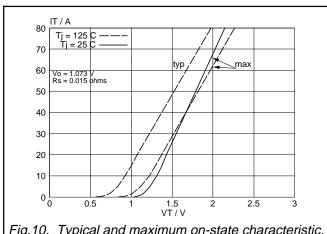
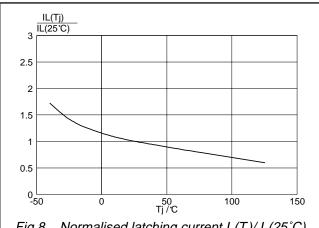


Fig. 10. Typical and maximum on-state characteristic.



Normalised latching current $I_L(T_j)/I_L(25^{\circ}C)$, versus junction temperature T

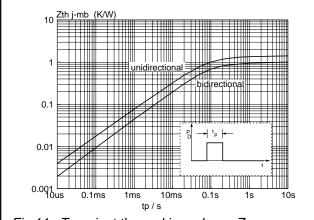


Fig.11. Transient thermal impedance $Z_{th i-mb}$, versus pulse width to.

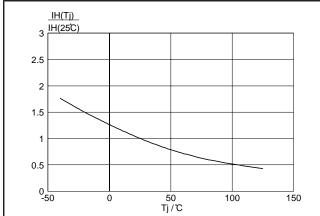


Fig.9. Normalised holding current $I_H(T_i)/I_H(25^{\circ}C)$, versus junction temperature T_i .

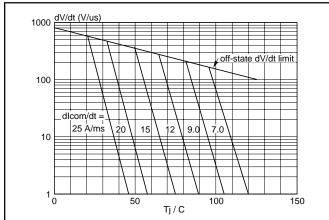
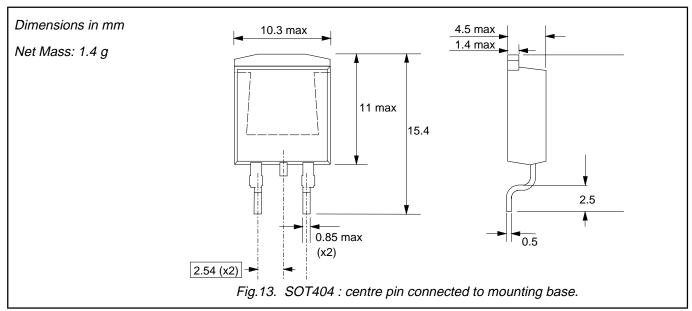


Fig.12. Typical commutation dV/dt versus junction temperature, parameter commutation dl_T/dt. The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation dl_r/dt.

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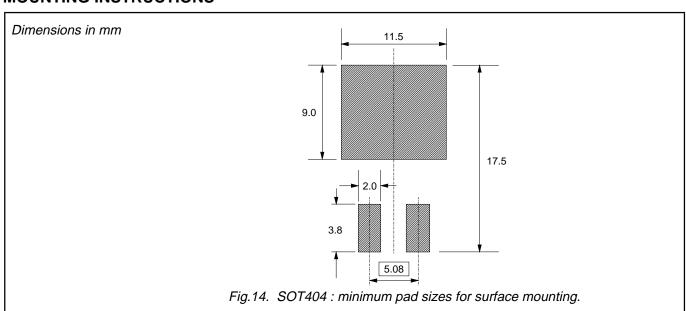
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
1 reduct op comeditors	This data direct contains intal product openingations.				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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